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FEMTOmini™ Diodes in the SOD-923 package









features

CMAD4448 (Switching Diode) **CMAD6001** (Low Leakage Diode) CMASH-4 (Schottky Diode) **CMAD6263**

(Schottky Diode)

Designed for today's electronic products with limited board space and package height restrictions, these new SOD-923 devices meet the strictest requirements, while maintaining high operational efficiency for portable handheld applications.

CMAD4448 (Switching Diode)

The CMAD4448 is a 120V, 250mA ultra high speed switching diode with a trr of 2.0ns (Typical) and 4.0ns (Maximum). Ideal for high speed switching applications.

CMAD6001 (Low Leakage Diode)

The CMAD6001 is a 100V, 250mA low leakage diode with an IR of 500pA (Maximum). This device also has a low capacitance of 2.0pF and a V_F of 0.85V at 1.0mA.

CMASH-4 (Schottky Diode)

The CMASH-4 is an energy efficient 40V, 200mA Schottky diode, boasting a low forward voltage drop of 0.35V (Typical) and 0.38V (Maximum) at 1.0mA.

CMAD6263 (Schottky Diode)

The CMAD6263 is an energy efficient 70V, 15mA Schottky diode, boasting a low forward voltage drop of 0.395V (Typical) and 0.410V (Maximum) at 1.0mA.

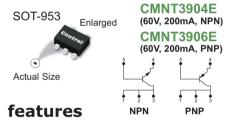


FEMTOmini™ Transistors in the SOT-953 package









VCE(SAT) of 0.2V @ 50mA

(1.05 x 1.05mm Max)

• Low Profile (0.5mm Max)

• Space Saving SOT-953 package

Space Saving SOD-923 package

 $(1.10 \times 0.65 \text{mm Max})$

• Low Profile (0.41mm Max)

• Ideal for battery powered and hand held applications

• Fast Switching, Low Leakage,

and Schottky diodes available

The CMNT3904E and CMNT3906E are NPN and PNP Low V_{CE} (SAT) transistors designed for applications where energy efficiency, ultra small size, and reasonable power dissipation are the prime requirements. Packaged in the **FEMTOmini**™ SOT-953 package, these devices provide performance characteristics suitable for the most demanding size constrained applications.

The Central Semiconductor CFSH-4 and CFSH2-4L are high quality Schottky

Package (TLP™), these devices are ideal for a wide range of power

Diodes designed for applications where ultra small size and reasonable power dissipation are prime requirements. Packaged in the SOD-882L Tiny Leadless

applications

- Voltage Clamping
- Protection Circuits
- DC/DC Converters Battery powered products including Cell Phones, Digital Cameras, Pagers, PDAs, Laptop Computers, etc.



Schottky Diodes in the New Ultra Low Profile SOD-882L Tiny Leadless Package (TLP™)











• Enhanced Specification including an improved

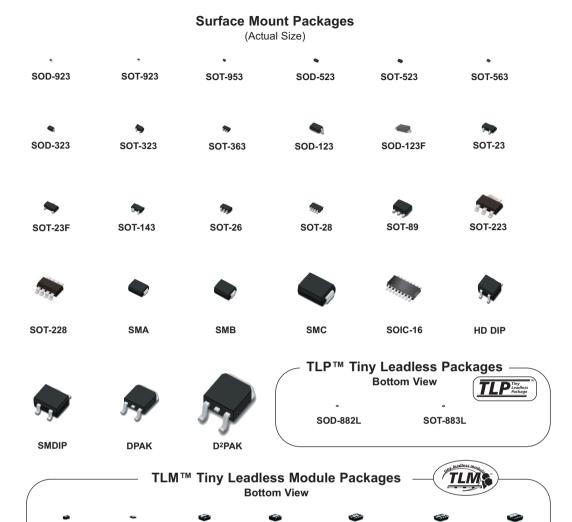
features

- Halogen Free by design
- Medium Current: (I_O=200mA)
- Low Forward Voltage Drop: CFSH-4 (V_F=0.35V TYP @ 1.0mA) CFSH2-4L (V_F=0.53V TYP @ 200mA)
- Low Reverse Current: **CFSH-4** (25nA TYP @ 30V) CFSH2-4L (350nA TYP @ 40V)

management applications.

- Extremely Fast Switching: (5ns Max)
- Leadless SOD-882L TLP™ case: 1.05mm x 0.65mm with an ultra low profile of 0.4mm

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TLM622

Device Families

TLM621

• Small Signal Transistors

TLM621H

TLM322

- Small Signal MOSFETs
- Junction FETs
- Power Transistors
- Switching Diodes
- Schottky Diodes
- Low and Ultra Low Leakage Diodes
- Zener Diodes

TLM832

- Transient Voltage Suppressors (TVS)
- Stabistors (Forward Reference Diodes)

TLM832D

- Current Limiting Diodes
- Rectifiers
- Bridge Rectifiers



For complete package details please visit: www.centralsemi.com/packagedetails

TLM833

For further information contact: Sales at Central Semiconductor Corp. (631) 435-1110 or visit our website at: www.centralsemi.com

Innovations in Discrete Semiconductors

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